FAIRCHILD

SEMICONDUCTOR®

FDP2710_F085 N-Channel PowerTrench[®] MOSFET

250V, 50A, 47mΩ

Features

- Typ $r_{DS(on)}$ = 38m Ω at V_{GS} = 10V, I_D = 50A
- Typ Q_{g(TOT)} = 78nC at V_{GS} = 10V
- Fast switching speed
- Low gate charge
- High performance trench technology for extremely low RDS(on)
- High power and current handling capability
- Qualified to AEC Q101
- RoHS Compliant

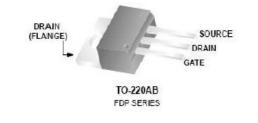
General Description

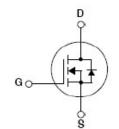
This N-Channel MOSFET is produced using Fairchil Semiconductor's advanced PowerTrench process that has been especially tailored to minimize the on-state resistance and yet maintain superior switching performance.

Applications

- PDP application
- Hybrid Electric Vehicle DC/DC converters







February 2010

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MOSF	MOSFET Maximum Ratings T _C = 25°C unless otherwise noted				
Symbol	Parameter	Ratings	Units		
V _{DSS}	Drain to Source Voltage	250	V		
V _{GS}	Gate to Source Voltage	±30	V		
	Drain Current Continuous (T _C < 50°C, V _{GS} = 10V)	50			
I _D	Continuous (T_{amb} = 25°C, V_{GS} = 10V, with $R_{\theta JA}$ = 62°C/W)	4	А		
	Pulsed	See Figure 4			
E _{AS}	Single Pulse Avalanche Energy (Not	e 1) 483	mJ		
Р	Power Dissipation	403	W		
P _D	Derate above 25°C	3.2	W/ºC		
T _J , T _{STG}	Operating and Storage Temperature	-55 to +150	°C		

Thermal Characteristics

$R_{ ext{ heta}JC}$	Maximum Thermal Resistance Junction to Case		0.31	°C/W
R_{\thetaJA}	Maximum Thermal Resistance Junction to Ambient (N	ote 2)	62	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDP2710	FDP2710_F085	TO220	Tube	NA	50 units
Electrical Characteristics - associate strand					

Electrical Characteristics $T_C = 25^{\circ}C$ unless otherwise noted

Symbol Parameter Test Conditions Min Typ Ma	Units	Max	Тур	Min	Test Conditions	Parameter	Symbol
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Off Characteristics

B _{VDSS}	Drain to Source Breakdown Voltage	$I_D = 250 \mu A, V_{GS} = 0V$		250	-	-	V
ΔBV_{DSS} / ΔT_{J}	Breakdown Voltage Temperature Coefficient	I_D = 250µA, Referenced to 25°C		-	0.25	-	V/°C
1	Zero Gate Voltage Drain Current	V _{DS} = 250V,		-	-	1	μA
IDSS	Zero Gate voltage Drain Current	$V_{GS} = 0V$	T _C = 125 ^o C	-	-	500	μΑ
I _{GSS}	Gate to Source Leakage Current	V_{GS} = ±30V		-	-	±100	nA

On Characteristics

V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu A$	3	3.9	5	V
		I _D = 50A, V _{GS} = 10V,	-	38	47	
r _{DS(on)}	Drain to Source On Resistance	$I_D = 50A, V_{GS} = 10V,$ $T_J = 150^{\circ}C$	-	104	129	mΩ
9 FS	Forward Transconductance	I _D = 25A, V _{DS} = 10V	-	63	-	S

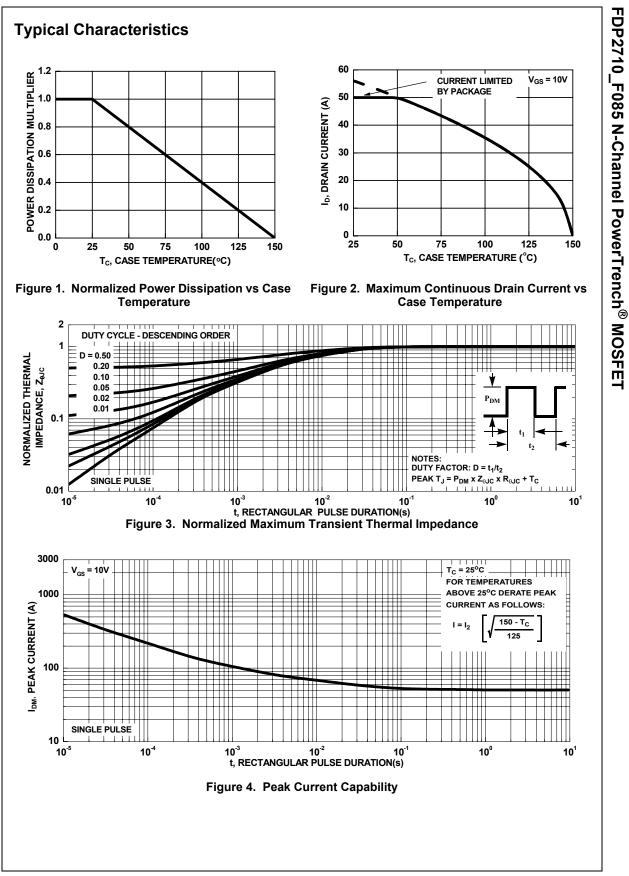
Dynamic Characteristics

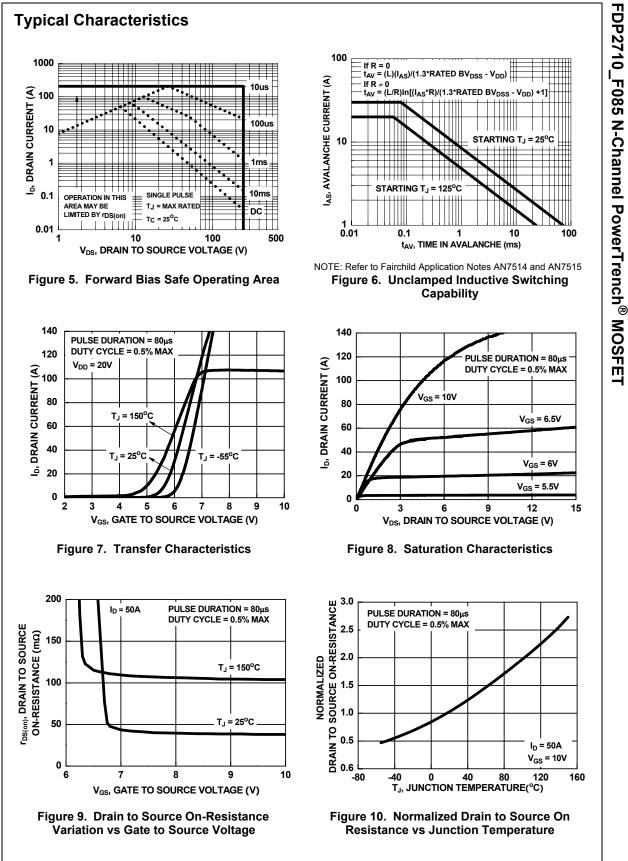
C _{iss}	Input Capacitance	V _{DS} = 25V, V _{GS} = 0V, f = 1MHz		-	5690	-	pF
C _{oss}	Output Capacitance			-	425	-	pF
C _{rss}	Reverse Transfer Capacitance			-	115	-	pF
Q _{g(TOT)}	Total Gate Charge at 20V	V _{GS} = 0 to 10V		-	78	101	nC
Q _{gs}	Gate to Source Gate Charge		V _{DD} = 125V I _D = 50A	-	31	-	nC
Q _{gd}	Gate to Drain "Miller" Charge		ID - 207	-	20	-	nC

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Switch	ing Characteristics					
t _{d(on)}	Turn-On Delay Time		-	85	-	ns
t _r	Rise Time	V_{DD} = 125V, I _D = 50A V_{GS} = 10V, R _{GEN} = 25 Ω	-	183	-	ns
t _{d(off)}	Turn-Off Delay Time		-	140	-	ns
t _f	Fall Time		-	121	-	ns
Drain-So	Maximum Continuous Drain-Source		-	-	50	A
I _{SM}	Maximum Pulsed Drain-Source Dio	de Forward Current	-	-	150	Α
V _{SD}	Source to Drain Diode Voltage	I _{SD} = 50A	-	0.9	1.2	V
t _{rr}	Reverse Recovery Time	I _{SD} = 50A, dI _{SD} /dt = 100A/μs	-	166	216	ns
Q _{rr}	Reverse Recovery Charge	$_{\rm SD}$ = 50A, $_{\rm SD}$ / $_{\rm USD}$ / $_{\rm USD}$		1	1.3	uC

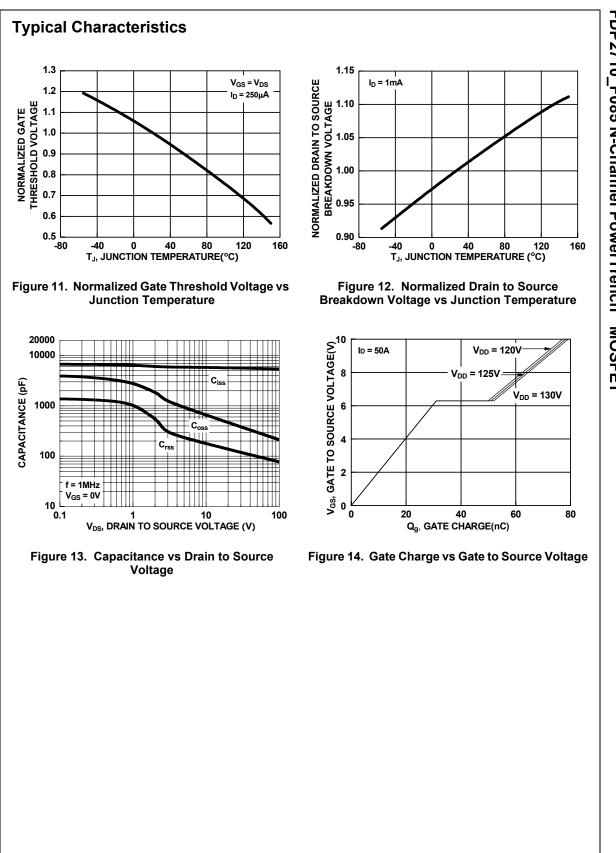
1: Starting $T_J = 25^{\circ}C$, L = 1.68mH, $I_{AS} = 24A$. 2: Pulse width 100s

This product has been designed to meet the extreme test conditions and environment demanded by the automotive industry. For a copy of the requirements, see AEC Q101 at: http://www.aecouncil.com/ All Fairchild Semiconductor products are manufactured, assembled and tested under ISO9000 and QS9000 quality systems certification.





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Datasheet Identification	Product Status	Definition		
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Preliminary First Production		Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.		
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.		
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.		